TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

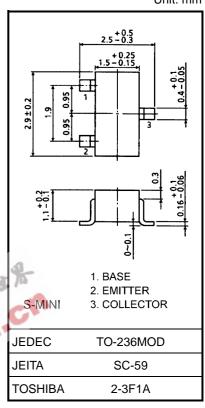
# 2SC2532

Audio Frequency Amplifier Applications Driver Stage for LED Lamp Applications Temperature Compensation Applications

• High hFE: hFE (1) = 5000 (min) (IC = 10 mA) hFE (2) = 10000 (min) (IC = 100 mA)

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V <sub>CBO</sub>	40	V	
Collector-emitter voltage	V <sub>CEO</sub>	40	V	
Emitter-base voltage	V <sub>EBO</sub>	10	V	
Collector current	Ι <sub>C</sub>	300	mA	4.
Base current	Ι <sub>Β</sub>	60	mA	34
Collector power dissipation	P <sub>C</sub>	150	mW	1
Junction temperature	Тj	125	°C	
Storage temperature range	T <sub>stg</sub>	-55~125	°C	

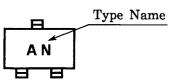


#### Weight: 0.012 g (typ.)

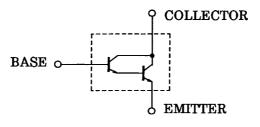
#### Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 40 V, I_E = 0$	_	_	0.1	μA
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB} = 8 V, I_{C} = 0$	_	_	0.1	μA
DC current gain		h <sub>FE</sub> (1)	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	5000	_	_	
		h <sub>FE</sub> (2)	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	10000			
Collector-emitter saturation vol	tage	V <sub>CE (sat)</sub>	$I_C = 300 \text{ mA}, I_B = 0.3 \text{ mA}$	_	0.9	1.3	V
Base-emitter voltage		V <sub>BE</sub>	$V_{CB} = 2 \text{ V}, \text{ I}_{C} = 100 \text{ mA}$	_	1.25	1.6	V

#### Marking



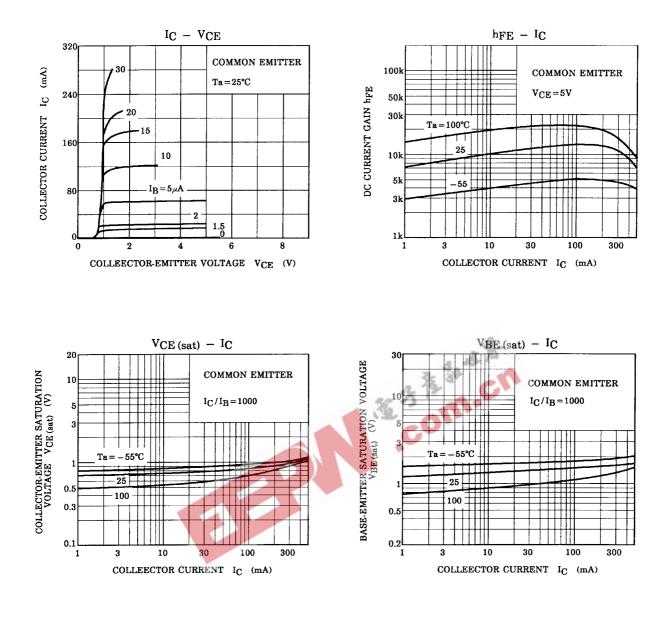
#### Equivalent Circuit

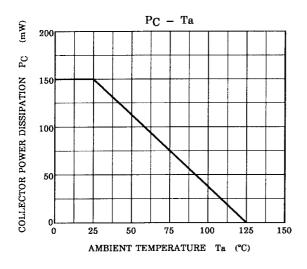




Unit: mm

## **TOSHIBA**





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